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### 3.3V CMOS 32-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS AND BUS-HOLD

### IDT74ALVCH32245

#### **FEATURES**:

- 0.5 MICRON CMOS Technology
- Typical tSK(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- Vcc = 2.5V ± 0.2V
- CMOS power levels (0.4µ W typ. static)
- · Rail-to-Rail output swing for increased noise margin
- Available in 96-ball LFBGA package

#### **DRIVE FEATURES:**

- High Output Drivers: ±24mA
- Suitable for Heavy Loads

#### **APPLICATIONS:**

- 3.3V high speed systems
- 3.3V and lower voltage computing systems

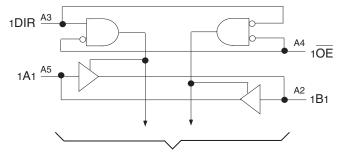
### DESCRIPTION:

This 32-bit bus transceiver is built using advanced dual metal CMOS technology. This high-speed, low power transceiver is ideal for asynchronous communication between two busses (A and B). The Direction and Output Enable controls are designed to operate the device as either four independent 8-bit transceivers or one 32-bit transceiver. The direction control pins (DIR) control the direction of data flow. The output enable pins  $(\overline{OE})$  override the direction control and disable both ports. All inputs are designed with hysteresis for improved noise margin.

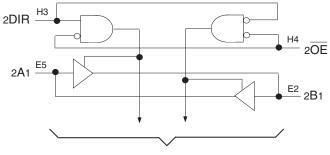
The ALVCH32245 has been designed with a  $\pm$ 24mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

The ALVCH32245 has "bus-hold" which retains the inputs' last state whenever the input bus goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

### FUNCTIONAL BLOCK DIAGRAM

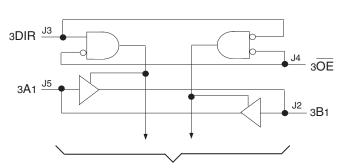


TO SEVEN OTHER CHANNELS

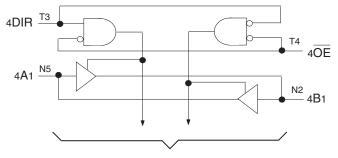


TO SEVEN OTHER CHANNELS

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TO SEVEN OTHER CHANNELS



TO SEVEN OTHER CHANNELS

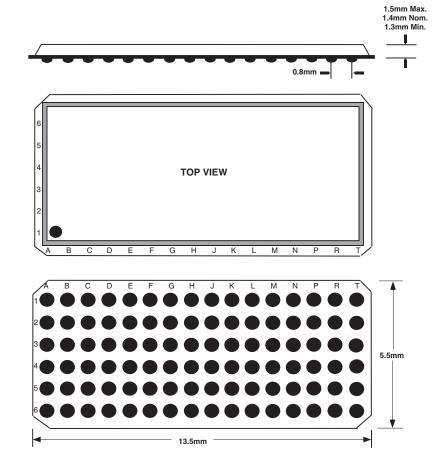
## **JUNE 2016**



6	1 <b>A</b> 2	1 <b>A</b> 4	1 <b>A</b> 6	1 <b>A</b> 8	2 <b>A</b> 2	2 <b>A</b> 4	2 <b>A</b> 6	2 <b>A</b> 7	3 <b>A</b> 2	3 <b>A</b> 4	3 <b>A</b> 6	3 <b>A</b> 8	4 <b>A</b> 2	4 <b>A</b> 4	4 <b>A</b> 6	4 <b>A</b> 7
5	1 <b>A</b> 1	1 <b>A</b> 3	1 <b>A</b> 5	1 <b>A</b> 7	2A1	2 <b>A</b> 3	2 <b>A</b> 5	2 <b>A</b> 8	3 <b>A</b> 1	3 <b>A</b> 3	3 <b>A</b> 5	3 <b>A</b> 7	4 <b>A</b> 1	4 <b>A</b> 3	4 <b>A</b> 5	4 <b>A</b> 8
4	10E	GND	Vcc	GND	GND	Vcc	GND	20E	зŌЕ	GND	Vcc	GND	GND	Vcc	GND	40E
3	1DIR	GND	Vcc	GND	GND	Vcc	GND	2DIR	зDIR	GND	Vcc	GND	GND	Vcc	GND	4DIR
2	1B1	1B3	1B5	1B7	2B1	2B3	2B5	2B8	3B1	3B3	3B5	3B7	4B1	4B3	4 <b>B</b> 5	4B8
1	1B2	1B4	1B6	1B8	2B2	2B4	2B6	2B7	3B2	3B4	3B6	3B8	4B2	4B4	4B6	4B7
	A	В	С	D	E	F	G	Н	J	ĸ	L	М	N	Р	R	Т

LFBGA TOPVIEW

#### 96 BALL LFBGA PACKAGE ATTRIBUTES



#### IDT74ALVCH32245 3.3V CMOS 32-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

#### **INDUSTRIAL TEMPERATURE RANGE**

### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Terminal Voltage with Respect to GND	–0.5 to +4.6	V
VTERM <sup>(3)</sup>	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
Tstg	Storage Temperature	–65 to +150	°C
Ιουτ	DC Output Current	–50 to +50	mA
Ік	Continuous Clamp Current, VI < 0 or VI > Vcc	±50	mA
Іок	Continuous Clamp Current, Vo < 0	50	mA
lcc Iss	Continuous Current through each Vcc or GND	±100	mA

#### NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc.

### **PIN DESCRIPTION**

Pin Names	Description	
xOE Output Enable Inputs (Active LOW)		
xDIR	xDIR Direction Control Inputs	
xAx	Side A Inputs or 3-State Outputs <sup>(1)</sup>	
xBx	Side B Inputs or 3-State Outputs <sup>(1)</sup>	

NOTE:

1. These pins have "Bus-Hold". All other pins are standard inputs, outputs, or I/Os.

#### **CAPACITANCE** (TA = +25°C, F = 1.0MHz)

Symbol	Parameter <sup>(1)</sup>	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	5	7	рF
Соит	Output Capacitance	Vout = 0V	7	9	рF
CI/O	I/O Port Capacitance	VIN = 0V	7	9	рF

NOTE:

1. As applicable to the device type.

### FUNCTION TABLE (EACH 8-BIT SECTION)<sup>(1)</sup>

Inp	outs	
xOE	xDIR	Outputs
L	L	Bus B Data to Bus A
L	Н	Bus A Data to Bus B
Н	Х	High Z State

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level X = Don't Care

Z = High Impedance

### DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Operating Condition: TA = -40 °C to +85 °C

Symbol	Parameter	Test Co	nditions	Min.	Typ. <sup>(1)</sup>	Max.	Unit
Vih	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	_	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		_	-	0.7	V
		Vcc = 2.7V to 3.6V		_	_	0.8	
Іін	Input HIGH Current	Vcc = 3.6V	VI = VCC	_	—	±5	μA
lıL	Input LOW Current	Vcc = 3.6V	VI = GND	_	-	±5	μA
lozн	High Impedance Output Current	Vcc = 3.6V	Vo = Vcc	_	_	±10	μA
Iozl	(3-State Output pins)		Vo = GND	_	-	±10	
Viк	Clamp Diode Voltage	Vcc = 2.3V, IIN = -18mA			-0.7	-1.2	V
Vн	Input Hysteresis	Vcc = 3.3V		_	100	_	mV
ІССL ІССН ІССZ	Quiescent Power Supply Current	Vcc = 3.6V Vin = GND or Vcc		-	0.1	40	μA
ΔICC	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, other i	nputs at Vcc or GND	-	-	750	μA

NOTE:

1. Typical values are at Vcc = 3.3V, +25°C ambient.

### **BUS-HOLD CHARACTERISTICS**

Symbol	Parameter <sup>(1)</sup>	Test Conditions			Typ. <sup>(2)</sup>	Max.	Unit
Івнн	Bus-Hold Input Sustain Current	Vcc = 3V	VI = 2V	-75	—	_	μA
IBHL			VI = 0.8V	75	_	—	
Івнн	Bus-Hold Input Sustain Current	Vcc = 2.3V	VI = 1.7V	-45	—	_	μA
IBHL			VI = 0.7V	45	—	_	
Івнно	Bus-Hold Input Overdrive Current	Vcc = 3.6V	VI = 0 to 3.6V	_	—	±500	μA
Ibhlo							

NOTES:

1. Pins with Bus-Hold are identified in the pin description.

2. Typical values are at Vcc = 3.3V, +25°C ambient.

### **OUTPUT DRIVE CHARACTERISTICS**

Symbol	Parameter	Test Con	ditions <sup>(1)</sup>	Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	Іон = -0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	Iон = - 6mA	2	_	
		Vcc = 2.3V	Іон = – 12mA	1.7	_	
		Vcc = 2.7V		2.2	_	
		Vcc = 3V	]	2.4	_	
		Vcc = 3V	Iон = - 24mA	2	—	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	—	0.2	V
		Vcc = 2.3V	IOL = 6mA	—	0.4	
			IoL = 12mA	—	0.7	
		Vcc = 2.7V	IoL = 12mA	_	0.4	
		Vcc = 3V	IOL = 24mA	_	0.55	

NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = − 40°C to + 85°C.

### **OPERATING CHARACTERISTICS, TA = 25 °C**

			$Vcc = 2.5V \pm 0.2V$	$Vcc = 3.3V \pm 0.3V$	
Symbol	Parameter	Test Conditions	Typical	Typical	Unit
Cpd	Power Dissipation Capacitance per Driver Outputs enabled	CL = 0pF, f = 10Mhz	44	58	pF
Cpd	Power Dissipation Capacitance per Driver Outputs disabled		8	10	

### SWITCHING CHARACTERISTICS<sup>(1)</sup>

		Vcc = 2.	5V ± 0.2V	Vcc =	= 2.7V	Vcc = 3.3	3V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Unit
tPLH .	Propagation Delay	1	3.7	—	3.6	1	3	ns
<b>t</b> PHL	xAx to xBx or xBx to xAx							
tPZH	Output Enable Time	1	5.7	—	5.4	1	4.4	ns
tPZL	<del>XOE</del> to xAx to xBx							
tPHZ	Output Disable Time	1	5.2	—	4.6	1	4.1	ns
tPLZ	<del>XOE</del> to xAx to xBx							
tSK(O)	Output Skew <sup>(2)</sup>	_	_	_	_	_	500	ps

NOTES:

1. See TEST CIRCUITS AND WAVEFORMS. TA =  $-40^{\circ}$ C to + 85°C.

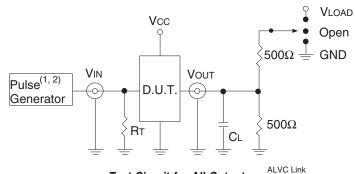
2 Skew between any two outputs of the same package and switching in the same direction.

#### IDT74ALVCH32245 3.3V CMOS 32-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

#### **INDUSTRIAL TEMPERATURE RANGE**

### **TEST CIRCUITS AND WAVEFORMS TEST CONDITIONS**

Symbol	Vcc <sup>(1)</sup> =3.3V±0.3V	Vcc <sup>(1)</sup> =2.7V	Vcc <sup>(2)</sup> =2.5V±0.2V	Unit
VLOAD	6	6	2 x Vcc	V
Vih	2.7	2.7	Vcc	V
Vт	1.5	1.5	Vcc/2	V
Vlz	300	300	150	mV
Vнz	300	300	150	mV
CL	50	50	30	pF



#### Test Circuit for All Outputs

#### **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

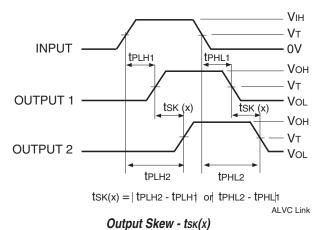
RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

#### NOTES:

1. Pulse Generator for All Pulses: Rate  $\leq$  1.0MHz: tF  $\leq$  2.5ns: tR  $\leq$  2.5ns. 2. Pulse Generator for All Pulses: Rate  $\leq$  1.0MHz; tF  $\leq$  2ns; tR  $\leq$  2ns.

#### SWITCH POSITION

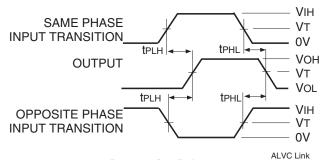
Test	Switch
Open Drain Disable Low Enable Low	Vload
Disable High Enable High	GND
All Other Tests	Open



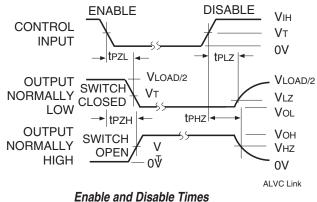
#### NOTES:

For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs. 1.

For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank. 2

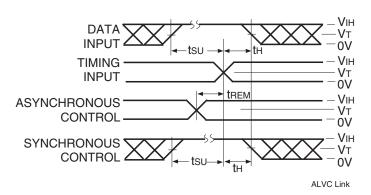




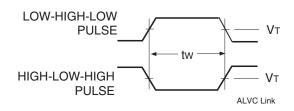


#### NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.



#### Set-up, Hold, and Release Times

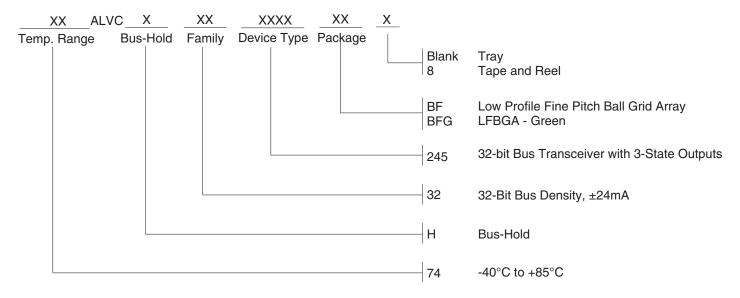


Pulse Width

#### IDT74ALVCH32245 3.3V CMOS 32-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

**INDUSTRIAL TEMPERATURE RANGE** 

#### ORDERINGINFORMATION



### DATASHEET DOCUMENT HISTORY

06/15/2016 Pg. 7 Updated the ordering information by adding Tape and Reel information.

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